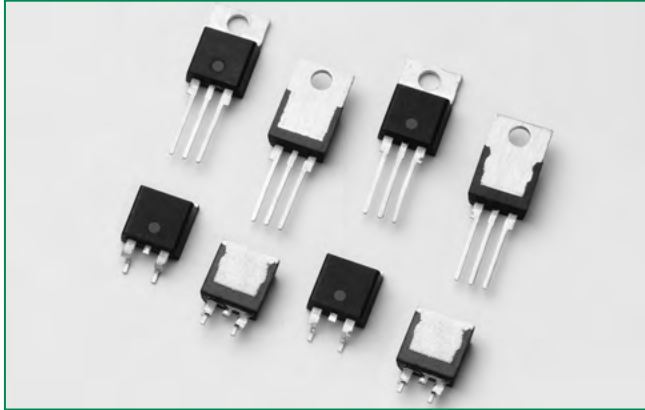



SJxx32xxA Series



Note: xx = voltage/10, x=package

Agency Recognitions

| Agency | Agency File Number |
|---|--------------------|
|  | E71639 |

Note: L package only

Main Features

| Symbol | Value | Unit |
|-------------------|------------|------|
| $I_{T(RMS)}$ | 32 | A |
| V_{DRM}/V_{RRM} | 400 or 600 | V |
| I_{GT} | 15 or 40 | mA |

Description

This SJxx32xxA high temperature SCR series is ideal for uni-directional switch applications such as phase control in heating, motor speed controls and AC rectifier and voltage regulator.

This SCR series offer low gate current trigger levels of 15 mA or 40 mA at approximately 1.5V.

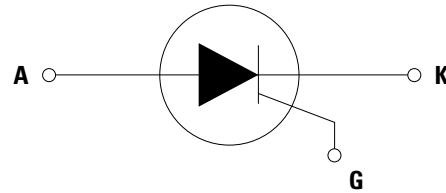
Features & Benefits

- High junction temperature
- Voltage capability up to 600 V
- Surge capability up to 380 A at 60 Hz half cycle
- AEC-Q101 qualified
- Recognized to UL 1557 as an Electrically Isolated Semiconductor Device
- Halogen-free and ROHS compliant

Applications

Typical applications are AC rectifier, voltage regulator, AC solid-state switches, industrial power tools, exercise equipment, white goods and commercial appliances.

Schematic Symbol



Absolute Maximum Ratings

| Symbol | Parameter | Test Conditions | Value | Unit |
|-------------------|---|---|------------|------------|
| V_{DSM}/V_{RSM} | Peak non-repetitive blocking voltage | $P_w = 100\mu s$ | 700 | V |
| $I_{T(RMS)}$ | RMS on-state current | SJxx32LxA $T_c = 80^\circ C$ | 32 | A |
| | | SJxx32RxA/SJxx32NxA $T_c = 115^\circ C$ | | |
| $I_{T(AV)}$ | Average on-state current | SJxx32LxA $T_c = 80^\circ C$ | 20 | A |
| | | SJxx32RxA/SJxx32NxA $T_c = 115^\circ C$ | | |
| I_{TSM} | Peak non-repetitive surge current | single half cycle; $f = 50Hz$; T_J (initial) = $25^\circ C$ | 320 | A |
| | | single half cycle; $f = 60Hz$; T_J (initial) = $25^\circ C$ | 380 | |
| I^2t | I^2t Value for fusing | $t_p = 8.3 ms$ | 640 | A^2s |
| di/dt | Critical rate of rise of on-state current | $f = 60Hz$; $T_J = 150^\circ C$ | 150 | $A/\mu s$ |
| I_{GM} | Peak gate current | $t_p \leq 10\mu s$; $T_J = 150^\circ C$ | 4 | A |
| $P_{G(AV)}$ | Average gate power dissipation | $t_p \leq 10\mu s$; $T_J = 150^\circ C$ | 1 | W |
| T_{stg} | Storage temperature range | | -40 to 150 | $^\circ C$ |
| T_J | Operating junction temperature range | | -40 to 150 | $^\circ C$ |

Electrical Characteristics ($T_J = 25^\circ\text{C}$, unless otherwise specified)

| Symbol | Test Conditions | | SJxx32xA | SJxx32x2A | Unit | |
|----------|--|------|----------|-----------|---------------|------------------|
| I_{GT} | $V_D = 12\text{V}; R_L = 30\ \Omega$ | MAX. | 40 | 15 | mA | |
| | | MIN. | 5 | 3 | | |
| V_{GT} | | MAX. | 1.5 | | V | |
| dv/dt | $V_D = V_{DRM}; \text{gate open}; T_J = 125^\circ\text{C}$ | 400V | MIN. | 650 | 400 | V/ μs |
| | | 600V | | 600 | 350 | |
| | $V_D = V_{DRM}; \text{gate open}; T_J = 150^\circ\text{C}$ | 400V | | 550 | - | |
| | | 600V | | 500 | - | |
| | $V_D = 67\%V_{DRM}; \text{gate open}; T_J = 150^\circ\text{C}$ | 400V | | - | 300 | |
| | | 600V | | - | 250 | |
| V_{GD} | $V_D = V_{DRM}; R_L = 3.3\ \text{k}\Omega; T_J = 150^\circ\text{C}$ | MIN. | 0.2 | | V | |
| I_H | $I_T = 400\text{mA}$ (initial) | MAX. | 60 | 50 | mA | |
| t_q | $I_T = 2\text{A}; t_p = 50\ \mu\text{s}; dv/dt = 5\text{V}/\mu\text{s}; di/dt = -30\text{A}/\mu\text{s}$ | MAX. | 35 | | μs | |
| t_{gt} | $I_G = 2 \times I_{GT}; \text{PW} = 15\ \mu\text{s}; I_T = 64\text{A}$ | TYP. | 2 | | μs | |

Note: xx = voltage/10, x=package

Static Characteristics

| Symbol | Test Conditions | | Value | Unit | |
|---------------------|--|---------------------------|-------|------|---------------|
| V_{TM} | $I_T = 64\text{A}; t_p = 380\ \mu\text{s}$ | MAX. | 1.6 | V | |
| I_{DRM} / I_{RRM} | @ V_{DRM} / V_{RRM} | $T_J = 25^\circ\text{C}$ | MAX. | 10 | μA |
| | | $T_J = 125^\circ\text{C}$ | | 2000 | |
| | | $T_J = 150^\circ\text{C}$ | | 4000 | |

Thermal Resistances

| Symbol | Parameter | Value | Unit |
|------------------|---------------------|-------|---------------------------|
| $R_{\theta(UC)}$ | SJxx32LxA | 1.9 | $^\circ\text{C}/\text{W}$ |
| | SJxx32RxA/SJxx32NxA | 0.8 | |

Note: xx = voltage, x = sensitivity & type

Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature

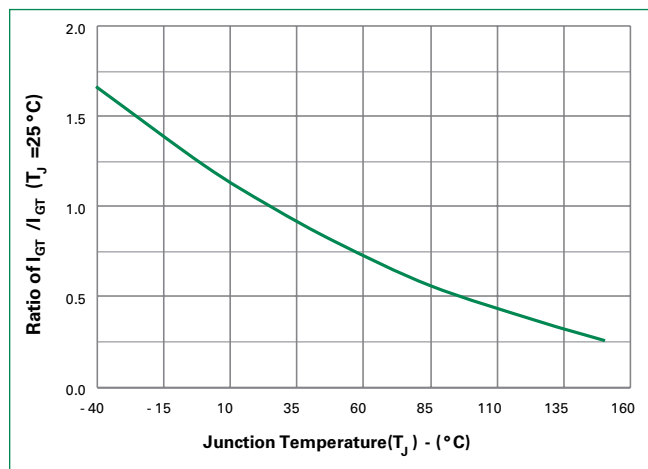


Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature

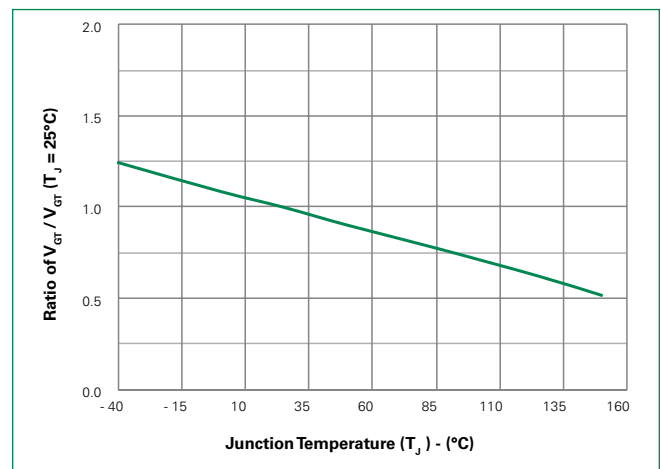


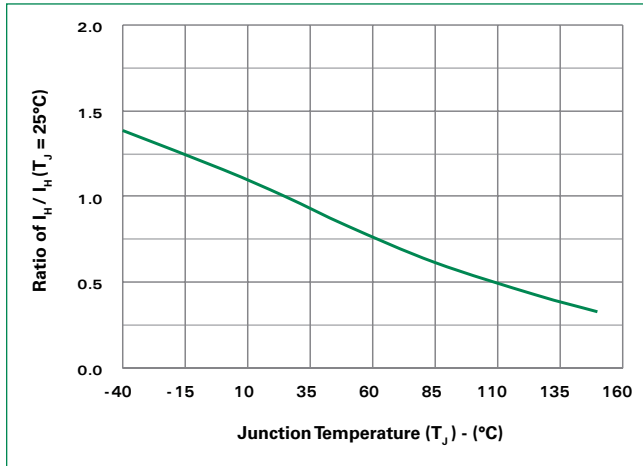
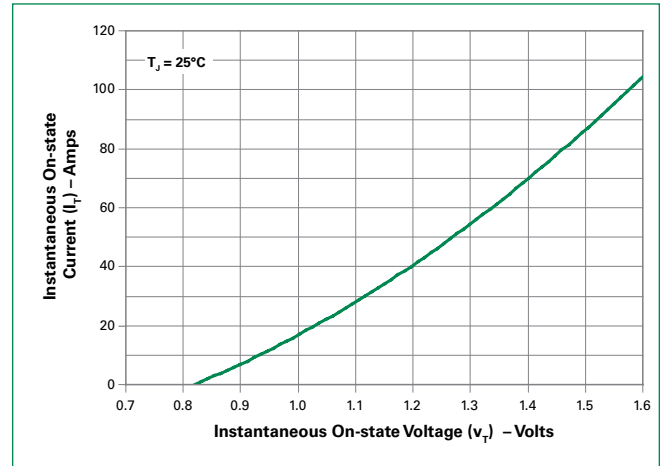
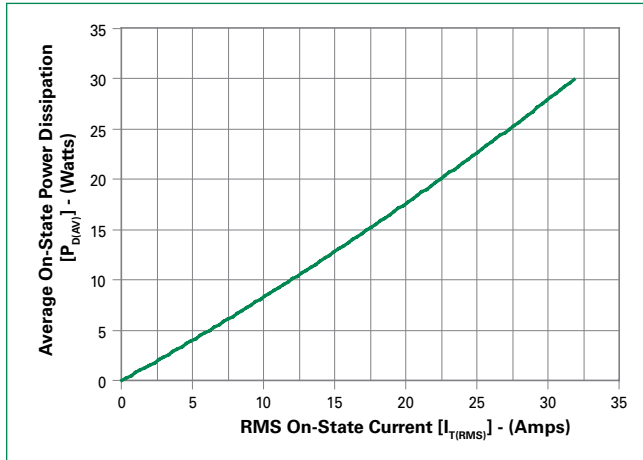
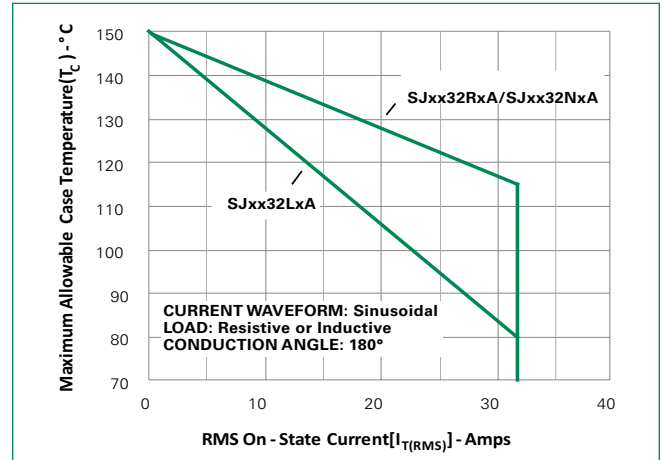
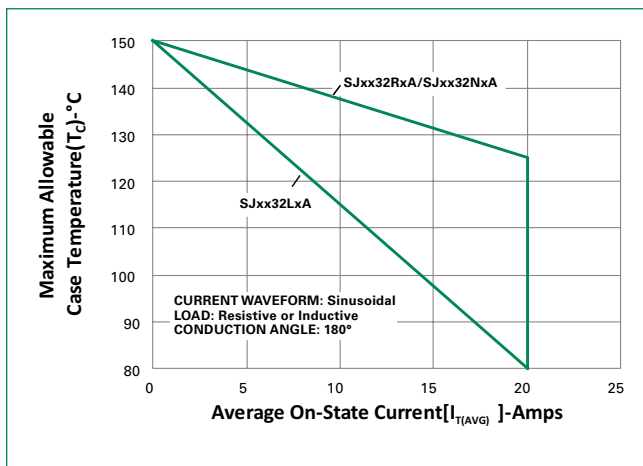
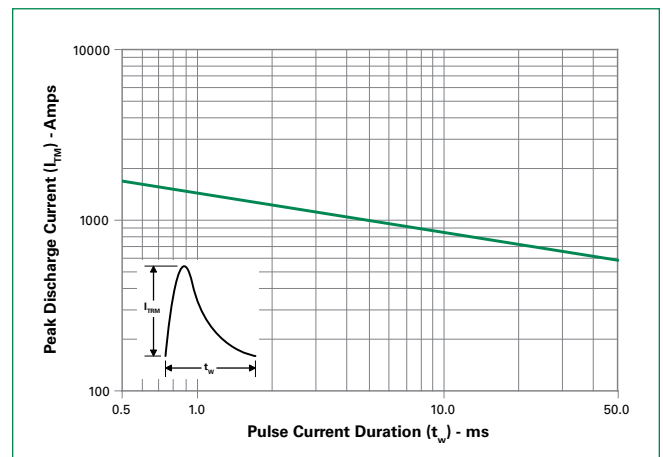
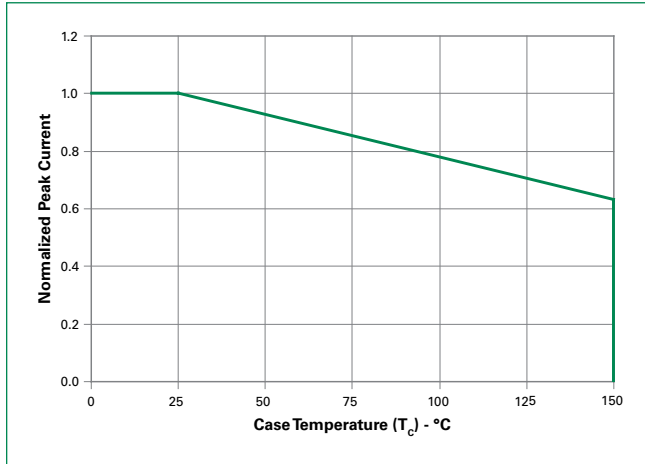
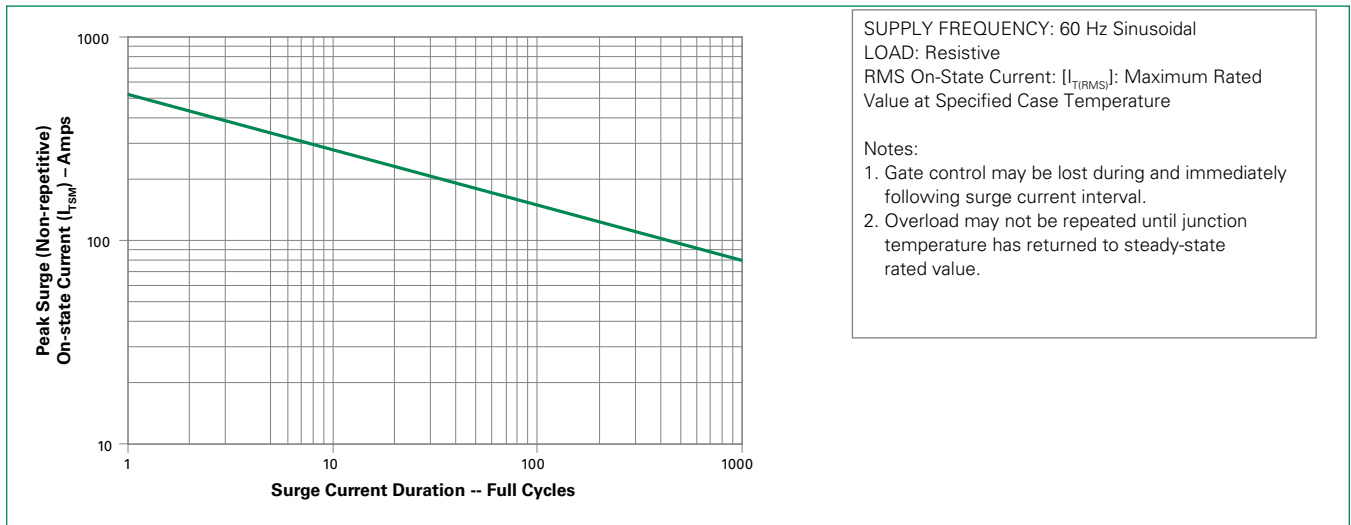
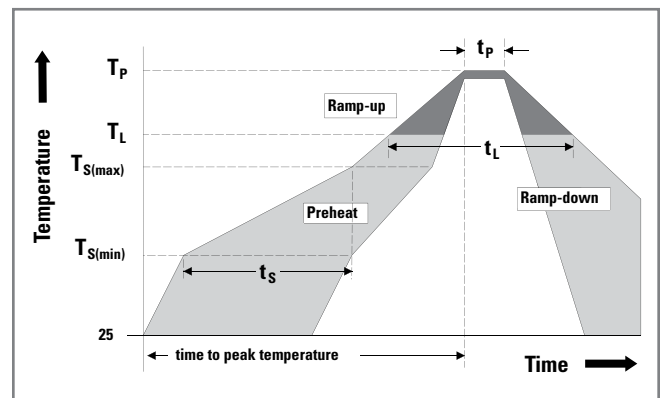
Figure 3: Normalized DC Holding Current vs. Junction Temperature

Figure 4: On-State Current vs. On-State Voltage (Typical)

Figure 5: Power Dissipation (Typical) vs. RMS On-State Current

Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current

Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current

Figure 8: Peak Capacitor Discharge Current


Figure 9: Peak Capacitor Discharge Current Derating

Figure 10: Surge Peak On-State Current vs. Number of Cycles

Soldering Parameters

| | | |
|--|------------------------------------|-------------------------|
| Reflow Condition | | Pb – Free assembly |
| Pre Heat | - Temperature Min ($T_{s(min)}$) | 150°C |
| | - Temperature Max ($T_{s(max)}$) | 200°C |
| | - Time (min to max) (t_s) | 60 – 180 secs |
| Average ramp up rate (Liquidus Temp) (T_L) to peak | | 5°C/second max |
| $T_{s(max)}$ to T_L - Ramp-up Rate | | 5°C/second max |
| Reflow | - Temperature (T_L) (Liquidus) | 217°C |
| | - Time (t_L) | 60 – 150 seconds |
| Peak Temperature (T_p) | | 260 ^{+0/-5} °C |
| Time within 5°C of actual peak Temperature (t_p) | | 20 – 40 seconds |
| Ramp-down Rate | | 5°C/second max |
| Time 25°C to peak Temperature (T_p) | | 8 minutes Max. |
| Do not exceed | | 280°C |



Physical Specifications

| | |
|------------------------|--|
| Terminal Finish | 100% Matte Tin-plated |
| Body Material | UL Recognized compound meeting flammability rating V-0 |
| Lead Material | Copper Alloy |

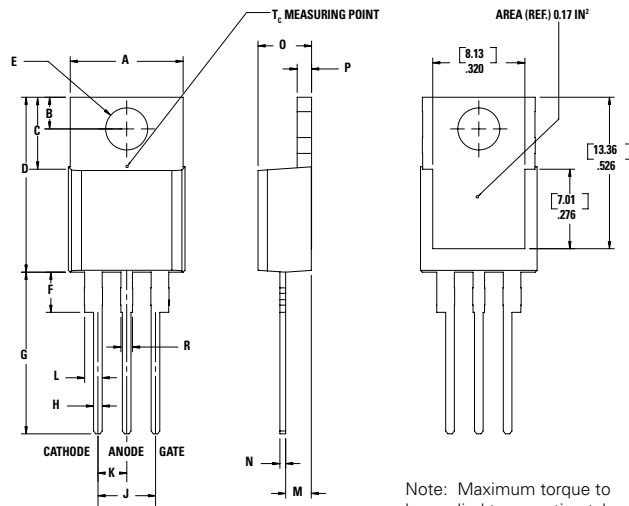
Design Considerations

Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

Environmental Specifications

| Test | Specifications and Conditions |
|-----------------------------------|--|
| AC Blocking | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 150°C for 1008 hours |
| Temperature Cycling | MIL-STD-750, M-1051, 1000 cycles; -55°C to +150°C; 15-min dwell-time |
| Temperature/Humidity | EIA / JEDEC, JESD22-A101 1008 hours; 160V - DC: 85°C; 85% rel humidity |
| Resistance to Solder Heat | MIL-STD-750 Method 2031 |
| Solderability | ANSI/J-STD-002, category 3, Test A |
| Lead Bend | MIL-STD-750, M-2036 Cond E |
| Moisture Sensitivity Level | Level 1, JEDEC-J-STD-020D |
| UHASt | JESD22A-118,96hrs, 130oC/85%RH |
| IOL | MIL-STD-750 Method 1037 |

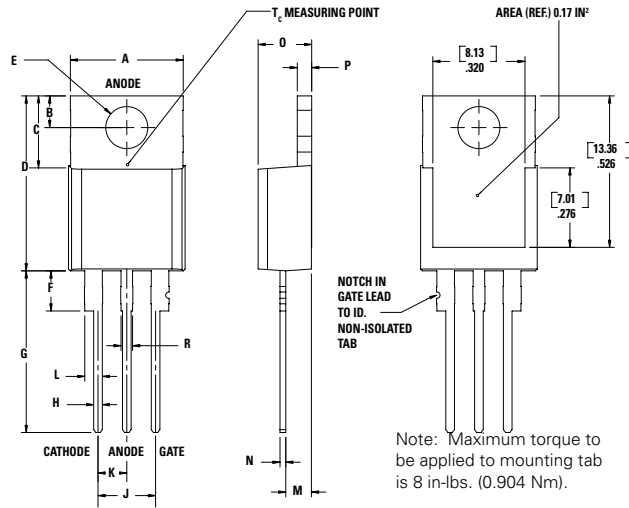
Dimensions — TO-220AB (L-Package) — Isolated Mounting Tab



Note: Maximum torque to be applied to mounting tab is 8 in-lbs. (0.904 Nm).

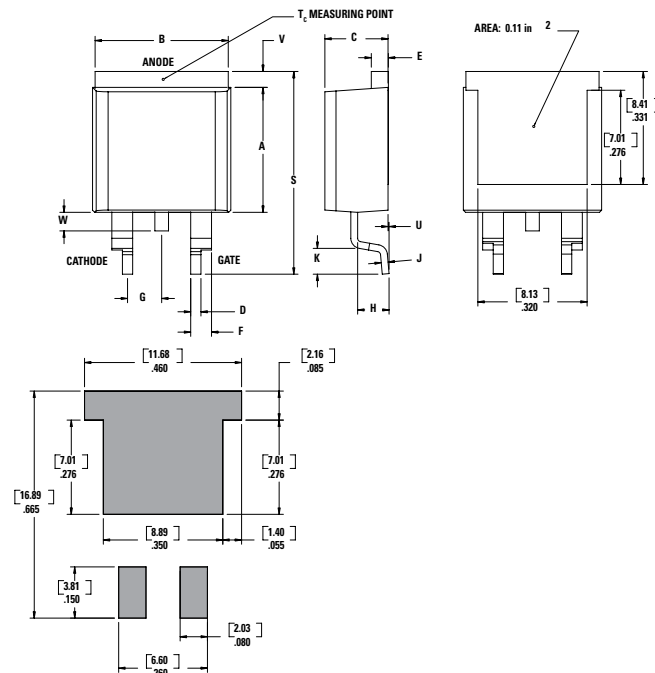
| Dimension | Inches | | Millimeters | |
|-----------|--------|-------|-------------|-------|
| | Min | Max | Min | Max |
| A | 0.380 | 0.420 | 9.65 | 10.67 |
| B | 0.105 | 0.115 | 2.67 | 2.92 |
| C | 0.230 | 0.250 | 5.84 | 6.35 |
| D | 0.590 | 0.620 | 14.99 | 15.75 |
| E | 0.142 | 0.147 | 3.61 | 3.73 |
| F | 0.110 | 0.130 | 2.79 | 3.30 |
| G | 0.540 | 0.575 | 13.72 | 14.61 |
| H | 0.025 | 0.035 | 0.64 | 0.89 |
| J | 0.195 | 0.205 | 4.95 | 5.21 |
| K | 0.095 | 0.105 | 2.41 | 2.67 |
| L | 0.060 | 0.075 | 1.52 | 1.91 |
| M | 0.085 | 0.095 | 2.16 | 2.41 |
| N | 0.018 | 0.024 | 0.46 | 0.61 |
| O | 0.178 | 0.188 | 4.52 | 4.78 |
| P | 0.045 | 0.060 | 1.14 | 1.52 |
| R | 0.038 | 0.048 | 0.97 | 1.22 |

Dimensions – TO-220AB (R-Package) – Non-Isolated Mounting Tab Common with Center Lead



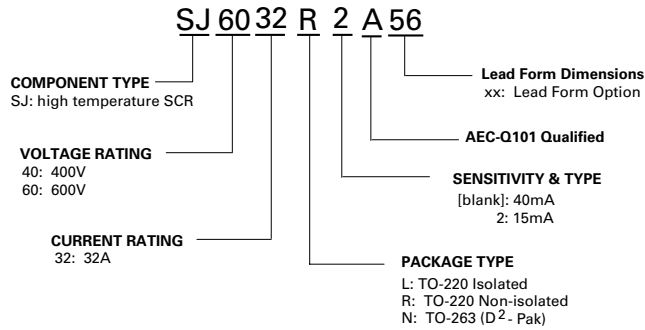
| Dimension | Inches | | Millimeters | |
|-----------|--------|-------|-------------|-------|
| | Min | Max | Min | Max |
| A | 0.380 | 0.420 | 9.65 | 10.67 |
| B | 0.105 | 0.115 | 2.67 | 2.92 |
| C | 0.230 | 0.250 | 5.84 | 6.35 |
| D | 0.590 | 0.620 | 14.99 | 15.75 |
| E | 0.142 | 0.147 | 3.61 | 3.73 |
| F | 0.110 | 0.130 | 2.79 | 3.30 |
| G | 0.540 | 0.575 | 13.72 | 14.61 |
| H | 0.025 | 0.035 | 0.64 | 0.89 |
| J | 0.195 | 0.205 | 4.95 | 5.21 |
| K | 0.095 | 0.105 | 2.41 | 2.67 |
| L | 0.060 | 0.075 | 1.52 | 1.91 |
| M | 0.085 | 0.095 | 2.16 | 2.41 |
| N | 0.018 | 0.024 | 0.46 | 0.61 |
| O | 0.178 | 0.188 | 4.52 | 4.78 |
| P | 0.045 | 0.060 | 1.14 | 1.52 |
| R | 0.038 | 0.048 | 0.97 | 1.22 |

Dimensions – TO-263 (N-package) – D²-Pak Surface Mount

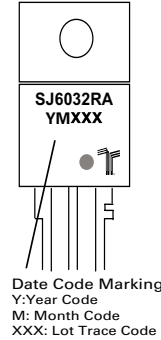


| Dimension | Inches | | Millimeters | |
|-----------|--------|-------|-------------|-------|
| | Min | Max | Min | Max |
| A | 0.360 | 0.370 | 9.14 | 9.40 |
| B | 0.380 | 0.420 | 9.65 | 10.67 |
| C | 0.178 | 0.188 | 4.52 | 4.78 |
| D | 0.025 | 0.035 | 0.63 | 0.89 |
| E | 0.048 | 0.055 | 1.22 | 1.40 |
| F | 0.060 | 0.075 | 1.52 | 1.91 |
| G | 0.095 | 0.105 | 2.41 | 2.67 |
| H | 0.083 | 0.093 | 2.11 | 2.36 |
| J | 0.018 | 0.024 | 0.46 | 0.61 |
| K | 0.090 | 0.110 | 2.29 | 2.79 |
| S | 0.590 | 0.625 | 14.99 | 15.87 |
| V | 0.035 | 0.045 | 0.89 | 1.14 |
| U | 0.002 | 0.010 | 0.05 | 0.25 |
| W | 0.040 | 0.070 | 1.02 | 1.78 |

Part Numbering System



Part Marking System



Product Selector

| Part Number | Voltage | | Gate Sensitivity | Type | Package |
|-------------|---------|------|------------------|--------------|---------|
| | 400V | 600V | | | |
| SJxx32LA | X | X | 40mA | Standard SCR | TO-220L |
| SJxx32RA | X | X | 40mA | Standard SCR | TO-220R |
| SJxx32NA | X | X | 40mA | Standard SCR | TO-263 |
| SJxx32L2A | X | X | 15mA | Standard SCR | TO-220L |
| SJxx32R2A | X | X | 15mA | Standard SCR | TO-220R |
| SJxx32N2A | X | X | 15mA | Standard SCR | TO-263 |

Note: xx = Voltage/10

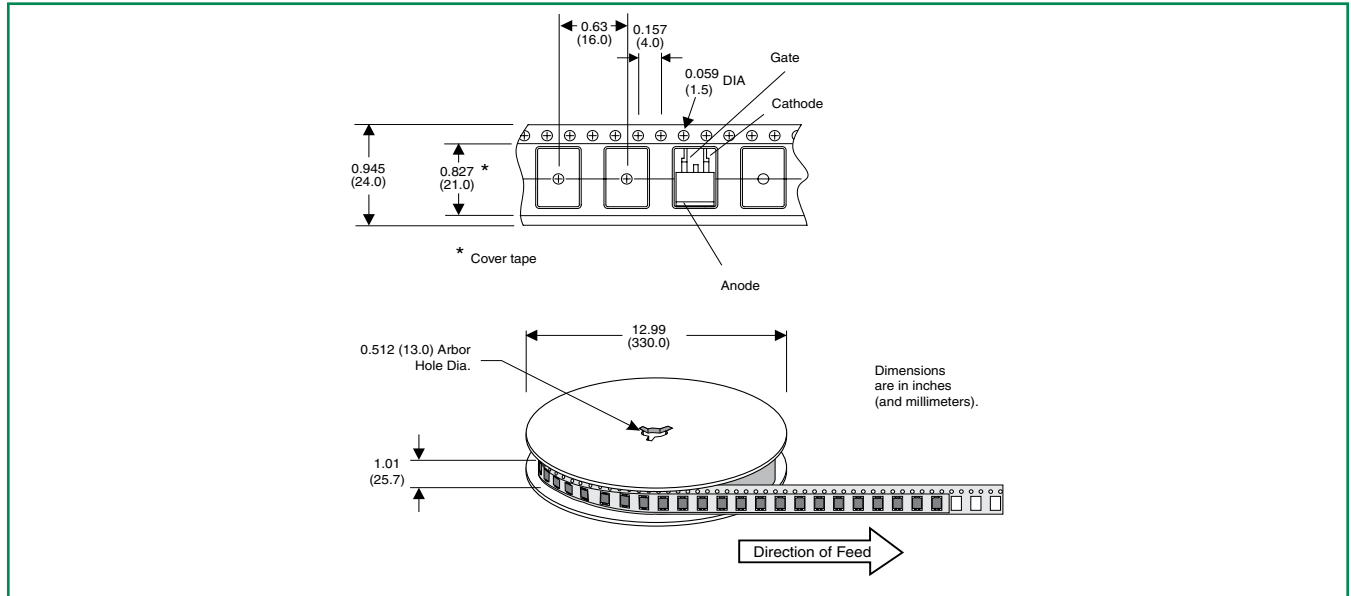
Packing Options

| Part Number | Marking | Weight | Packing Mode | Base Quantity |
|-------------|-----------|--------|------------------|--------------------|
| SJxx32LATP | SJxx32LA | 2.2g | Tube | 1000 (50 per tube) |
| SJxx32RATP | SJxx32RA | 2.2g | Tube | 1000 (50 per tube) |
| SJxx32NATP | SJxx32NA | 1.6g | Tube | 1000 (50 per tube) |
| SJxx32NARP | SJxx32NA | 1.6g | Embossed Carrier | 500 |
| SJxx32L2ATP | SJxx32L2A | 2.2g | Tube | 1000 (50 per tube) |
| SJxx32R2ATP | SJxx32R2A | 2.2g | Tube | 1000 (50 per tube) |
| SJxx32N2ARP | SJxx32N2A | 1.6g | Embossed Carrier | 500 |
| SJxx32N2ATP | SJxx32N2A | 1.6g | Tube | 1000 (50 per tube) |

Note: xx = Voltage/10

Reel Pack (RP) for TO-263 Embossed Carrier Specifications

Meets all EIA-481-2 Standards



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